

HT77xxSA 200mA PFM Synchronous Step-up DC/DC Converter

Features

- Low start-up voltage: 0.7V (Typ.)
- High efficiency: 2.7V ≤ V_{OUT} ≤ 5.0V upper 90% (Typ.)
- High output voltage accuracy: ±2.5%
- Output voltage: 2.7V, 3.0V, 3.3V, 5.0V
- Output current up to 200mA
- Ultra low supply current I_{DD}: 5μA (Typ.)
- · Low ripple and low noise
- Low shutdown current: 0.1µA (Typ.)
- TO92, SOT89, SOT23 and SOT23-5 package

Applications

- Palmtops/PDAs
- · Portable communicators/Smartphones
- Cameras/Camcorders
- · Battery-powered equipment

General Description

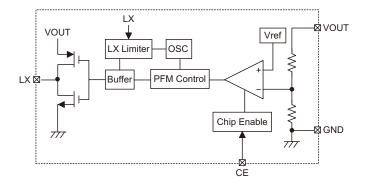
The HT77xxSA devices are a high efficiency PFM synchronous step-up DC-DC converter series which are designed to operate with both wire wound chip power inductors and also with multi-layered chip power inductors. The device series have the advantages of extremely low start-up voltage as well as high output voltage accuracy. Being manufactured using CMOS technology ensures ultra low supply current. Because of their higher operating frequency, up to 500 kHz, the devices have the benefits of requiring smaller outline type lower value external inductors and capacitors. The higher operating frequency also offers the advantages of much reduced audio frequency noise. The devices require only three external components to provide a fixed output voltage of 2.7V, 3.0V, 3.3V or 5.0V.

The HT77xxSA devices include an internal oscillator, PFM control circuit, driver transistor, reference voltage unit and a high speed comparator. They employ pulse frequency modulation techniques, to obtain minimum supply current and ripple at light output loading. These devices are available in space saving TO92, SOT89, SOT23 and SOT23-5 packages. For SOT23-5 package types, they also include an internal chip enable function to reduce power consumption when in the shutdown mode.

Selection Table

Part No.	Output Voltage	Tolerance	Package
HT7727SA	2.7V		TO92
HT7730SA	3.0V	10.50/	SOT89
HT7733SA	3.3V	±2.5%	SOT23
HT7750SA	5.0V		SOT23-5

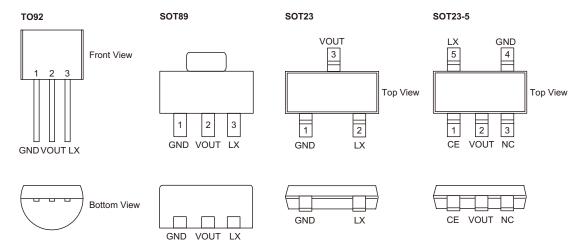
Block Diagram



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Pin Assignment



Pin Description

	Pin	No.		Pin Name	Description
TO92	SOT89	SOT23	SOT23-5	Pin Name	Description
_	_	_	1	CE	Chip enable pin, high active
2	2	3	2	VOUT	DC/DC converter output monitoring pin
_	_	_	3	NC	No connection
1	1	1	4	GND	Ground pin
3	3	2	5	LX	Switching pin

Absolute Maximum Ratings

Maximum Input Supply Voltage	6.5V	Storage Temperature	50°C to 125°C
Ambient Temperature Range	-40°C to 85°C		

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

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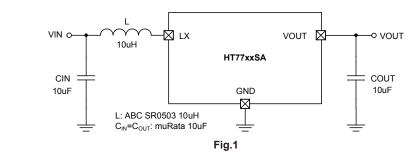


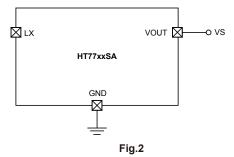
Electrical Characteristics

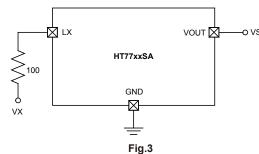
Ta= 25°C; V_{IN}= V_{OUT}×0.6; I_{OUT}= 10mA; unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{IN}	Input Voltage		_	_	6.0	V
ΔV_{OUT}	Output Voltage Tolerance	_	-2.5	_	+2.5	%
V _{START}	Starting Voltage(Fig.1)	V _{IN} : 0 to 2V, I _{OUT} =1mA	_	0.7	0.9	V
V _{HOLD}	Voltage Hold(Fig.1)	V _{IN} : 2 to 0V, I _{OUT} =1mA	_	_	0.7	V
I _{DD1}	Supply Current (Fig.2)	V _s =V _{OUT} +0.5V, Measured at VOUT Pin	_	5.0	_	μА
I _{DD2}	Un-load Supply Current (Fig.1)	V _{IN} =V _{OUT} ×0.6, I _{OUT} =0mA Measurement at LX	_		_	μΑ
I _{SHDN}	Shutdown Current	CE=GND	_	0.1	_	μA
	Current Limit (Fig. 1)	V _{OUT} ≤ 5.0V	650	800	_	mA
Limit	Current Limit (Fig.1)	2.7V ≤ V _{OUT} ≤ 3.3V	500	650	_	mA
V _{IH}	CE High Threshold		2.0	_	_	V
V _{IL}	CE Low Threshold	_	_	_	0.4	V
I _{LEAK}	LX Leakage Current (Fig.3)	V _s =5.5V, V _x =4V Measurement at the LX pin	_	0.05	_	μΑ
f _{osc}	Oscillator Frequency (Fig.3)	V _s =V _{OUT} ×0.95	_	500	_	kHz
D _{osc}	Oscillator Duty Cycle (Fig.3)	Measurement at the LX pin	_	80	_	%
η	Efficiency	2.7V ≤ V _{OUT} ≤ 5.0V, I _{OUT} =10mA	_	90	_	%

Note: Absolute maximum ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. The guaranteed specifications apply only for the test conditions listed.



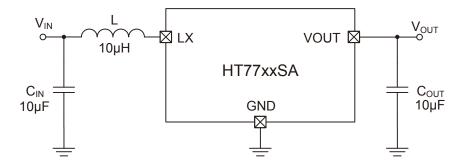




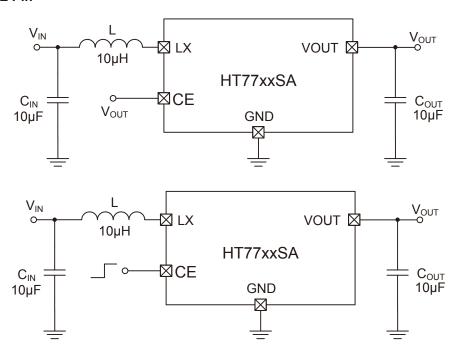


Application Circuits

Without CE Pin



With CE Pin



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Functional Description

The HT77xxSA is a constant on time synchronous stepup converter, which uses a pulse frequency modulation (PFM) controller scheme. The PFM control scheme is inherently stable. The required input/output capacitor and inductor selections will not create situations of instability.

The device includes a fully integrated synchronous rectifier which reduces costs (includes reduce L and C sizes, eliminates Schottky diode cost etc.) and board area. A true load disconnect function ensures that the device is completely shutdown.

Low Voltage Start-up

The devices have a very low start up voltage down to 0.7V. When power is first applied, the synchronous switch will be initially off but energy will be transferred to the load through its intrinsic body diode.

Shutdown

During normal device operation, the EN pin should be either high or connected to the VOUT pin or the VIN power source. When the device is in the shutdown mode, that is when the EN pin is pulled low, the internal circuitry will be switched off. During shutdown, the PMOS power transistor will be switched off thus placing the output into a floating condition.

Synchronous Rectification

A dead time exists between the N channel and P channel MOSFET switching operations. In synchronous rectification, the P channel is replaced by a Schottky diode. Here the P channel switch must be completely off before the N channel switch is switched on. After each cycle, a 30ns delay time is inserted to ensure the N channel switch is completely off before the P channel switch is switched on to maintain a high efficiency over a wide input voltage and output power range.

Application Information

Inductor Selection

Selecting a suitable inductor is an important consideration as it is usually a compromise situation between the output current requirements, the inductor saturation limit and the acceptable output voltage ripple. Lower values of inductor values can provide higher output currents but will suffer from higher ripple voltages and reduced efficiencies. Higher inductor values can provide reduced output ripple voltages and better efficiencies, but will be limited in their output current capabilities. For all inductors it must be noted however that lower core losses and lower DC resistance values will always provide higher efficiencies.

The peak inductor current can be calculated using the following equation:

$$I_{L(PEAK)} = \frac{V_{OUT} \times I_{O}}{V_{IN} \times \eta} + \frac{V_{IN} \times (V_{OUT} - V_{IN})}{2 \times V_{OUT} \times L}$$

Where

 V_{IN} = Input Voltage V_{OUT} = Output Voltage I_{O} = Output Current

 $\eta = Efficiency$

L = Inductor

Capacitor Selection

As the output capacitor selected affects both efficiency and output ripple voltage, it must be chosen with care to achieve best results from the converter. Output voltage ripple is the product of the peak inductor current and the output capacitor equivalent series resistance or ESR for short. It is important that low ESR value capacitors are used to achieve optimum performance. One method to achieve low ESR values is to connect two or more filter capacitors in parallel. The capacitors values and rated voltages are only suggested values.

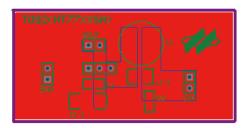


Layout Considerations

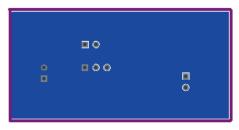
Circuit board layout is a very important consideration for switching regulators if they are to function properly.

Poor circuit layout may result in related noise problems. In order to minimise EMI and switching noise, note the following guidelines:

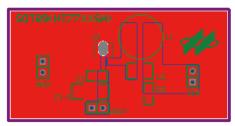
- All tracks should be as wide as possible.
- The input and output capacitors should be placed as close as possible to the VIN, VOUT and GND pins.
- A full ground plane is always helpful for better EMI performance.



Top Layer



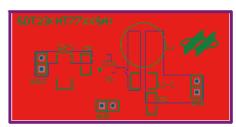
Bottom Layer



Top Layer



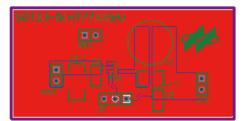
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Top Layer



Bottom Layer



Top Layer



Bottom Layer



Typical Performance Characteristics

HT7750SA

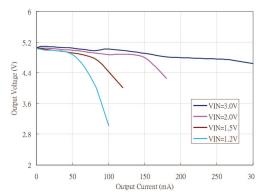
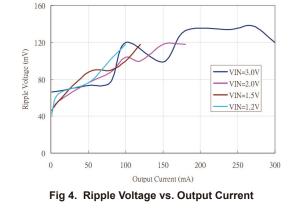


Fig 1. Output Voltage vs. Output Current



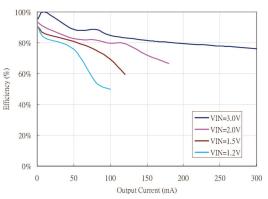


Fig 2. Efficiency vs. Output Current

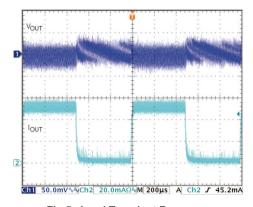


Fig 5. Load Transient Response (L=10 μ H, C_{IN}=C_{OUT}=10 μ F, V_{IN}=3.0V)

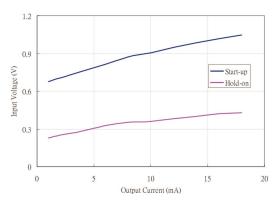


Fig 3. Start-up & Hold-on Voltage

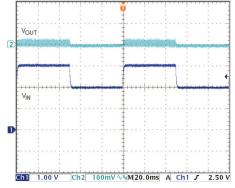


Fig 6. Line Transient Response (L=10 μ H, C_{IN}=C_{OUT}=10 μ F, V_{IN}=3.0V)

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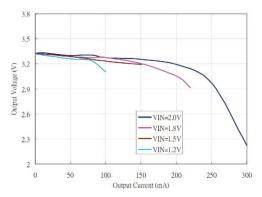


Fig 7. Output Voltage vs. Output Current0%

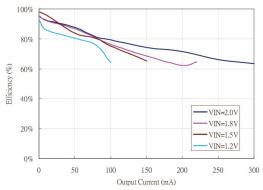


Fig 8. Efficiency vs. Output Current

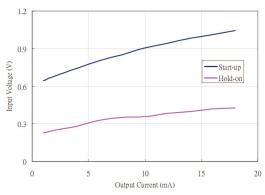


Fig 9. Start-up & Hold-on Voltage

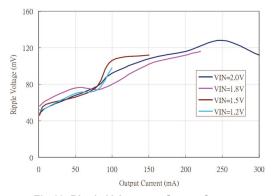


Fig 10. Ripple Voltage vs. Output Current

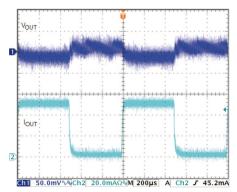


Fig 11. Load Transient Response (L=10 μ H, C_{IN}=C_{OUT}=10 μ F, V_{IN}=1.98V)

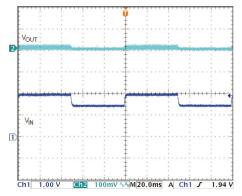


Fig 12. Line Transient Response (L=10 μ H, C_{IN}=C_{OUT}=10 μ F, V_{IN}=1.98V)

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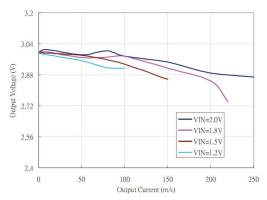


Fig 13. Output Voltage vs. Output Current

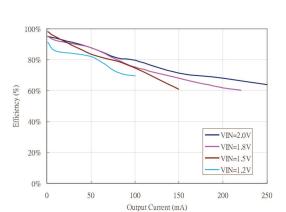


Fig 14. Efficiency vs. Output Current

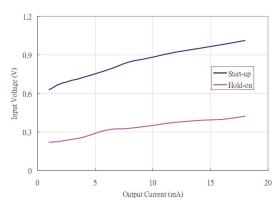


Fig 15. Start-up & Hold-on Voltage

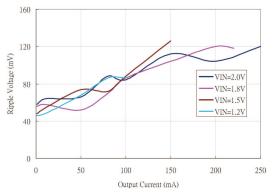


Fig 16. Ripple Voltage vs. Output Current

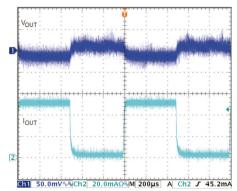


Fig 17. Load Transient Response (L=10 μ H, C_{IN}=C_{OUT}=10 μ F, V_{IN}=1.8V)

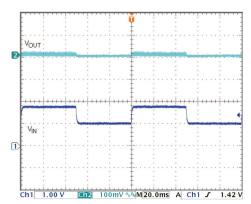


Fig 18. Line Transient Response (L=10 μ H, C_{IN}=C_{OUT}=10 μ F, V_{IN}=1.8V)

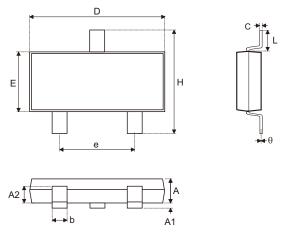
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Package Information

Note that the package information provided here is for consultation purposes only. As this information may be updated at regular intervals users are reminded to consult the Holtek website (http://www.holtek.com.tw/english/literature/package.pdf) for the latest version of the package information.

3-pin SOT23 Outline Dimensions



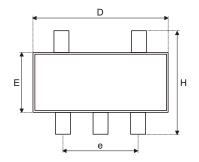
Symbol	Dimensions in inch				
Symbol	Min.	Nom.	Max.		
Α	0.039	_	0.051		
A1	_	_	0.004		
A2	0.028	_	0.035		
b	0.014	_	0.020		
С	0.004	_	0.010		
D	0.106	_	0.122		
E	0.055	_	0.071		
е	_	0.075	_		
Н	0.102	_	0.118		
L	0.015	_	_		
θ	0°	_	9°		

Symbol	Dimensions in mm				
Symbol	Min.	Nom.	Max.		
Α	1.00	_	1.30		
A1	_	_	0.10		
A2	0.70	_	0.90		
b	0.35	_	0.50		
С	0.10	_	0.25		
D	2.70	_	3.10		
E	1.40	_	1.80		
е	_	1.90	_		
Н	2.60	_	3.00		
L	0.37	_	_		
θ	0°	_	9°		

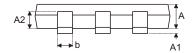
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5-pin SOT23-5 Outline Dimensions







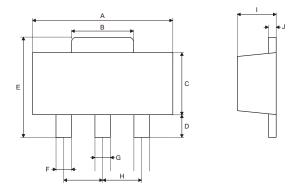
Sumb al	Dimensions in inch				
Symbol	Min.	Nom.	Max.		
Α	0.039	_	0.051		
A1	_	_	0.004		
A2	0.028	_	0.035		
b	0.014	_	0.020		
С	0.004	_	0.010		
D	0.106	_	0.122		
E	0.055	_	0.071		
е	_	0.075	_		
Н	0.102	_	0.118		
L	0.015	_	_		
θ	0°	_	9°		

Comple el	Dimensions in mm				
Symbol	Min.	Nom.	Max.		
А	1.00	_	1.30		
A1	_	_	0.10		
A2	0.70	_	0.90		
b	0.35	_	0.50		
С	0.10	_	0.25		
D	2.70	_	3.10		
E	1.40	_	1.80		
е	_	1.90	_		
Н	2.60	_	3.00		
L	0.37	_	_		
θ	0°	_	9°		

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3-pin SOT89 Outline Dimensions



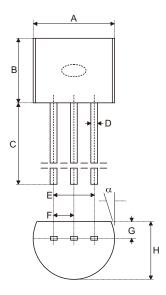
Symbol	Dimensions in inch				
Symbol	Min.	Nom.	Max.		
А	0.173	_	0.181		
В	0.059	_	0.072		
С	0.090	_	0.102		
D	0.035	_	0.047		
E	0.155	_	0.167		
F	0.014	_	0.019		
G	0.017	_	0.022		
Н	_	0.059	_		
I	55	_	63		
J	14	_	17		

Cumbal	Dimensions in mm				
Symbol	Min.	Nom.	Max.		
A	4.39	_	4.60		
В	1.50	_	1.83		
С	2.29	_	2.59		
D	0.89	_	1.19		
E	3.94	_	4.24		
F	0.36	_	0.48		
G	0.43	_	0.56		
Н	_	1.50	_		
I	1.40	_	1.60		
J	0.36	_	0.43		

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3-pin TO92 Outline Dimensions



Symbol	Dimensions in inch				
Symbol	Min.	Nom.	Max.		
А	0.170	_	0.200		
В	0.170	_	0.200		
С	0.500	_	_		
D	0.011	_	0.020		
E	0.090	_	0.110		
F	0.045	_	0.055		
G	0.045	_	0.065		
Н	0.130	_	0.160		
α	0°	_	10°		

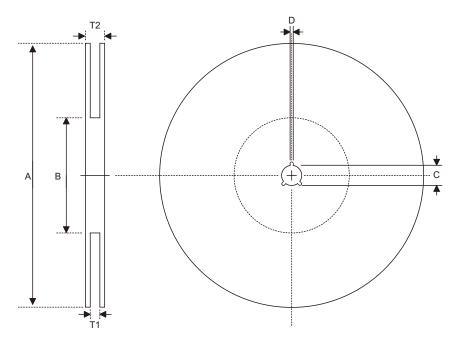
Symphol	Dimensions in mm				
Symbol	Min.	Nom.	Max.		
Α	4.32	_	5.08		
В	4.32	_	5.08		
С	12.70	_	_		
D	0.28	_	0.51		
E	2.29	_	2.79		
F	1.14	_	1.40		
G	1.14	_	1.65		
Н	3.30	_	4.06		
α	0°	_	10°		

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Product Tape and Reel Specifications

Reel Dimensions



SOT23-3, SOT23-5

Symbol	Description	Dimensions in mm
А	Reel Outer Diameter	178.0±1.0
В	Reel Inner Diameter	62.0±1.0
С	Spindle Hole Diameter	13.0±0.2
D	Key Slit Width	2.50±0.25
T1	Space Between Flange	8.4 +1.5/-0.0
T2	Reel Thickness	11.4 +1.5/-0.0

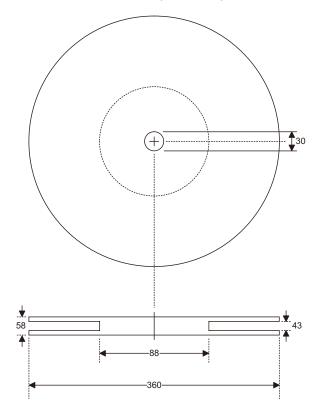
SOT89-3

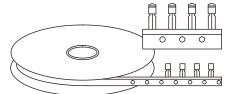
Symbol	Description	Dimensions in mm
А	Reel Outer Diameter	178.0±1.0
В	Reel Inner Diameter	62.0±1.0
С	Spindle Hole Diameter	13.0±0.2
D	Key Slit Width	2.50±0.25
T1	Space Between Flange	8.4 +1.5/-0.0
T2	Reel Thickness	11.4 +1.5/-0.0

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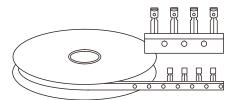


TO92 Reel Dimensions (Unit: mm)





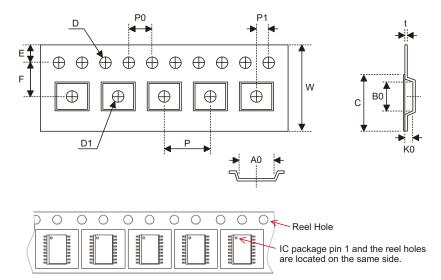
Package Up, Flat Side Up



Package Up, Flat Side Down



Carrier Tape Dimensions



SOT23-3, SOT23-5

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	8.0±0.3
Р	Cavity Pitch	4.0±0.1
E	Perforation Position	1.75±0.10
F	Cavity to Perforation (Width Direction)	3.50±0.05
D	Perforation Diameter	1.5 +0.1/-0.00
D1	Cavity Hole Diameter	1.5 +0.1/-0.00
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.00±0.05
A0	Cavity Length	3.15±0.10
В0	Cavity Width	3.2±0.1
K0	Cavity Depth	1.4±0.1
t	Carrier Tape Thickness	0.20±0.03
С	Cover Tape Width	5.3±0.1



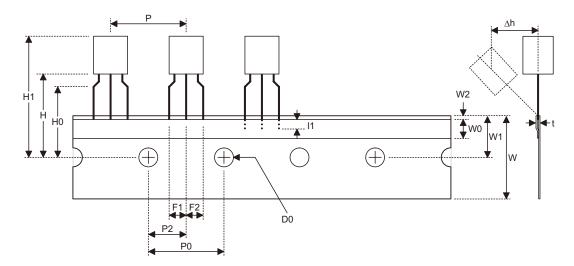
SOT89-3

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	12.0 ^{+0.3/-0.1}
Р	Cavity Pitch	8.0±0.1
E	Perforation Position	1.75±0.10
F	Cavity to Perforation (Width Direction)	5.50±0.05
D	Perforation Diameter	1.5 +0.1/-0.00
D1	Cavity Hole Diameter	1.5 +0.1/-0.00
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.0±0.1
A0	Cavity Length	4.8±0.1
В0	Cavity Width	4.5±0.1
K0	Cavity Depth	1.8±0.1
t	Carrier Tape Thickness	0.300±0.013
С	Cover Tape Width	9.3±0.1

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Carrier Tape Dimensions



TO92

Symbol	Description	Dimensions in mm
I1	Taped Lead Length	(2.5)
Р	Component Pitch	12.7±1.0
P0	Perforation Pitch	12.7±0.3
P2	Component to Perforation (Length Direction)	6.35±0.40
F1	Lead Spread	2.5 +0.4/-0.0
F2	Lead Spread	2.5 +0.4/-0.0
Δh	Component Alignment	0.0±0.1
W	Carrier Tape Width	18.0 +1.0/-0.5
W0	Hold-down Tape Width	6.0±0.5
W1	Perforation Position	9.0±0.5
W2	Hold-down Tape Position	(0.5)
H0	Lead Clinch Height	16.0±0.5
H1	Component Height	Less than 24.7
D0	Perforation Diameter	4.0±0.2
t	Taped Lead Thickness	0.7±0.2
Н	Component Base Height	19.0±0.5

Note: Thickness less than 0.38 ± 0.05 mm~0.5mm.

P0 Accumulated pitch tolerance: ±1mm/20pitches. () Bracketed figures are for reference only.

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